

Product Specification

XBLW LM285

Micropoer Voltage Reerence Diodes

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Descriptions

The LM285 series are micropower two-terminal bandgap voltage regulator diodes. Designed to operate over a wide current range of 10uA to 20mA, these devices feature exceptionally low dynamic impedance, low noise and stable operation over time and temperature. Tight voltage tolerances are achieved by on-chip trimming. The large dynamic operating range enables these devices to be used in applications with widely varying supplies with excellent regulation. Extremely low operating current make these devices ideal for micropower circuitry like portable instrumentation, regulators and other analog circuitry where extended battery life is required.

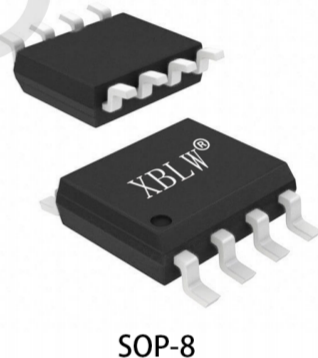
The LM285series are packaged in SOP-8, SOT23-3L and TO-92 plastic case and areavailable in versions of 1.24V、2.5V.

Features

- Operating Current from 10uA to 20mA
- 1% Initial Tolerance
- Low Temperature Coefficient
- 0.6Ω Dynamic Impedance
- Low Voltage Reference 1.24V

Applications

- Instrumentation
- Process Control
- Energy Management
- Data Acquisition Systems
- Battery-Powered Equipment
- Precision Audio Components

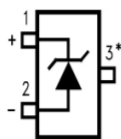


Ordering Information

Product Model	Package Type	Marking	Packing	Packing Qty
XBLW LM285Z-1.2	TO-92	LM285Z1.2	Bag	2000Pcs/Bag
XBLW LM285M3X-1.2	SOT23-3L	28512	Tape	3000Pcs/Reel
XBLW LM285MX-1.2	SOP-8	LM285M1.2	Tape	2500Pcs/Reel
XBLW LM285Z-2.5	TO-92	LM285Z2.5	Bag	2000Pcs/Bag
XBLW LM285M3X-2.5	SOT23-3L	28525	Tape	3000Pcs/Reel
XBLW LM285MX-2.5	SOP-8	LM285M2.5	Tape	2500Pcs/Reel

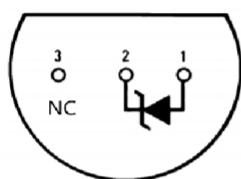
Pin Configurations Bottom View

Fixed Voltage versions

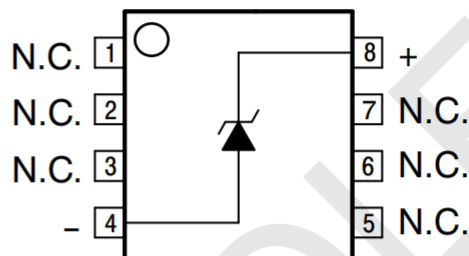


* Pin 3 is attached to the Die Attach Pad (DAP) and should be connected to Pin 2 or left floating.

SOT23-3L



TO-92



SOP-8

Function Block

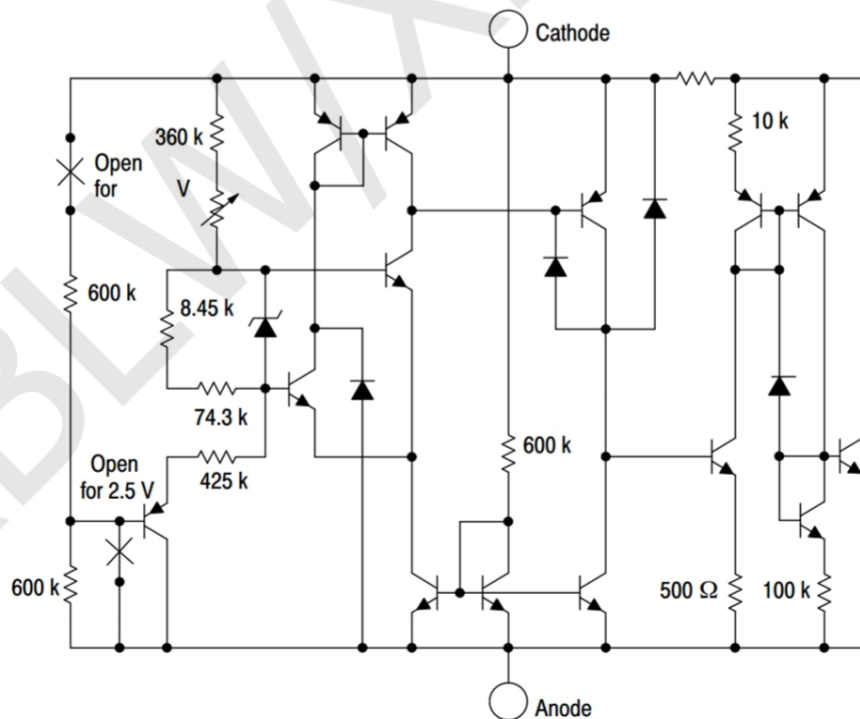


Figure1 Function Block Diagram of LM285

Absolute Maximum Ratings

(TA = 25°C, unless otherwise noted)

Characteristics	Symbol	Value	Unit
Reverse Current	IR	30	mA
Forward Current	IF	10	mA
Operating Ambient Temperature Range	TA	-40 to +85	°C
Operating Junction Temperature	TJ	+150	°C
Storage Temperature Range	Tstg	-65 ~ +150	°C
Electrostatic Discharge Sensitivity (ESD) Human Body Model (HBM) Machine Model (MM) Charged Device Model (CDM)	ESD	4000 400 2000	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

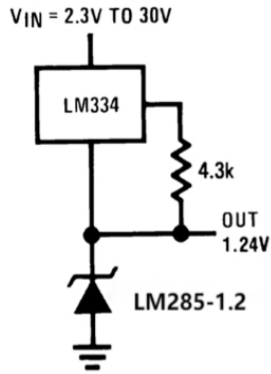
Electrical Characteristics

(TA = 25°C, unless otherwise noted)

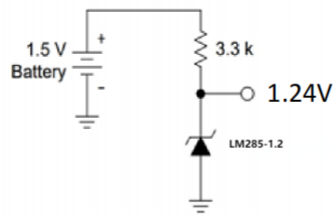
Characteristics	Symbol	Test Conditions	Min	Typ	Max	Unit
Reverse Breakdown Voltage LM285-1.2 LM285-2.5	V(BR)R	IRmin ≤ IR ≤ 20mA	1.220 2.475	1.240 2.500	1.250 2.525	V
Reverse Breakdown Voltage LM285-1.2 LM285-2.5		IRmin ≤ IR ≤ 20mA -40°C to +85°C	1.210 2.450		1.260 2.550	V
Minimum Operating Current	IRmin			6	10	μA
		-40°C to +85°C			20	μA
Reverse Breakdown Voltage Change with Current	ΔV(BR)R	IRmin ≤ IR ≤ 1mA			1.5	mV
		-40°C to +85°C			5	mV
		1mA ≤ IR ≤ 20mA		4	10	mV
		-40°C to +85°C			20	mV
Reverse Dynamic Impedance	Z	IR = 100μA		0.6		Ω
Average Temperature Coefficient	ΔV(BR)/ΔT	10μA ≤ IR ≤ 20 mA -40°C to +85°C		80		ppm/°C
Wideband Noise (RMS)	n	IR = 100μA, 10Hz ≤ f ≤ 10 kHz		60		μV
Long Term Stability	S	IR = 100μA, TA = +25°C ± 0.1°C		20		ppm/kHR

Typical Application Circuit

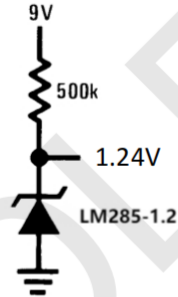
Fixed Vref Type Circuit



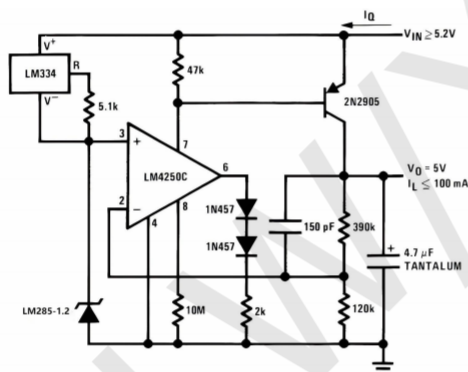
Wide Input Range Reference



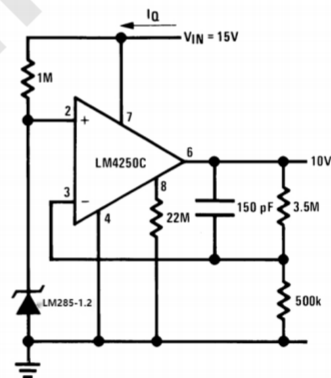
Reference from 1.5V Battery



Micropower Reference from 9V Battery



Micropower* 5V Regulator



Micropower* 10V Reference

Characteristics Curves

LM285-1.2/

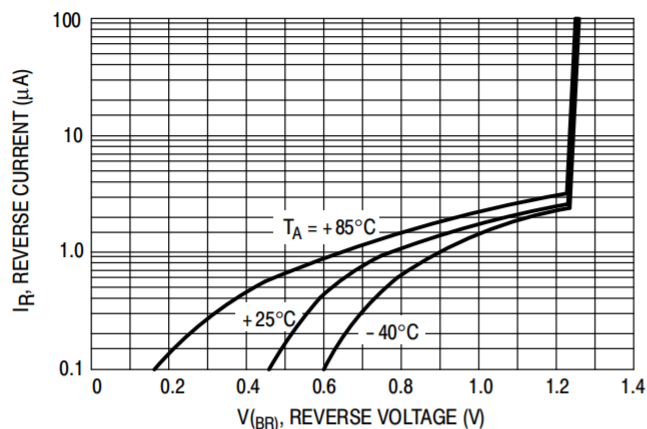


Figure 2. Reverse Characteristics

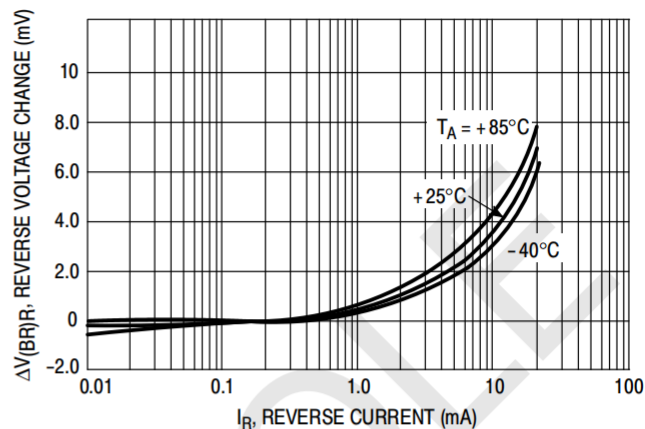


Figure 3. Reverse Characteristics

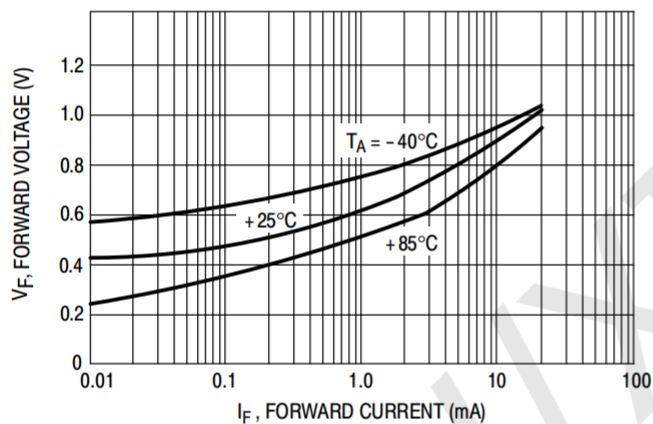


Figure 4. Forward Characteristics

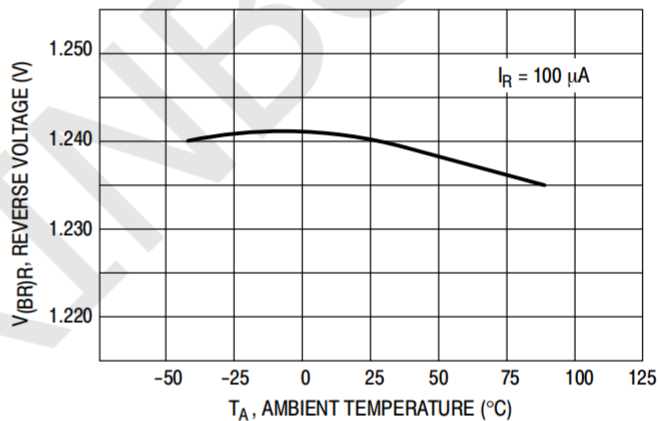


Figure 5. Temperature Drift

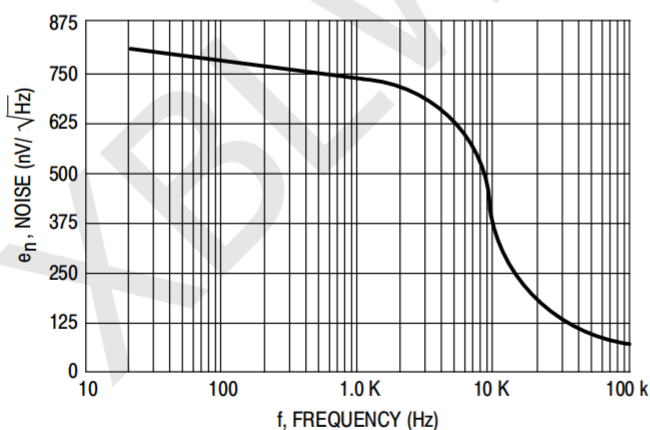


Figure 6. Noise Voltage

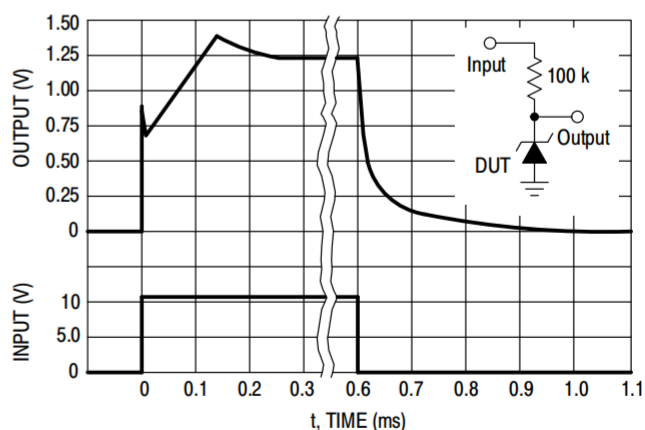


Figure 7. Response Time

LM285-2.5

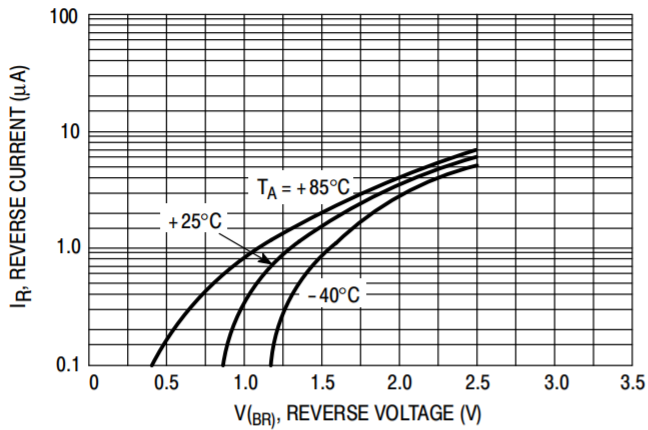


Figure 8. Reverse Characteristics

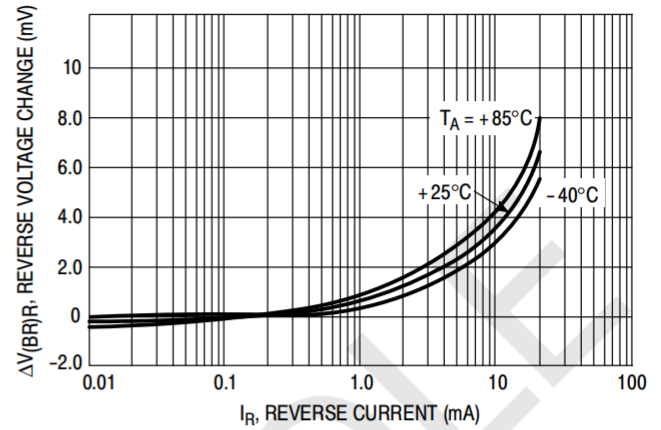


Figure 9. Reverse Characteristics

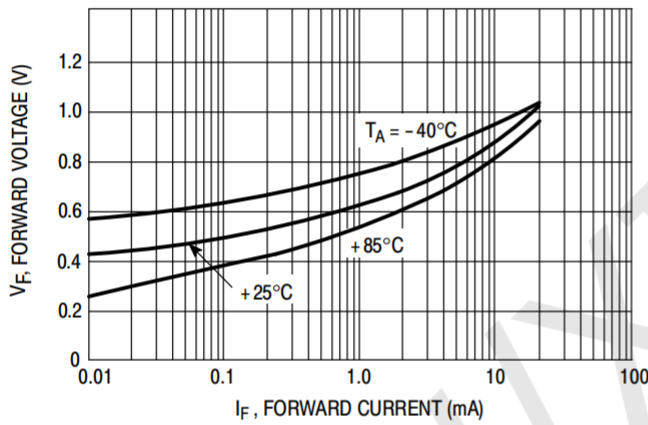


Figure 10. Forward Characteristics

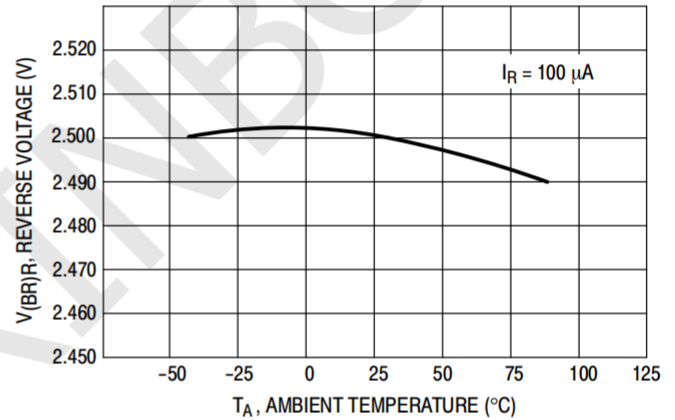


Figure 11. Temperature Drift

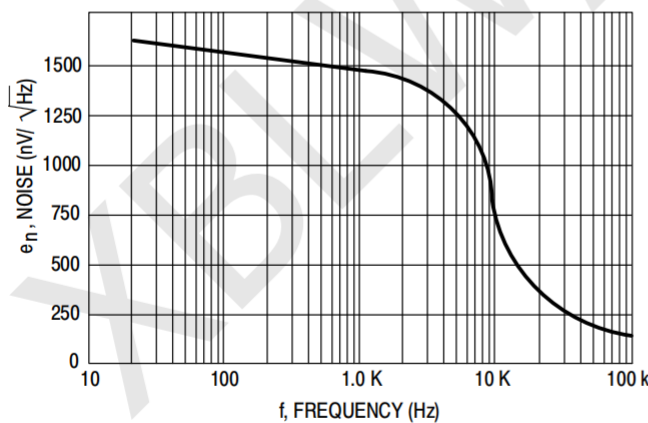


Figure 12. Noise Voltage

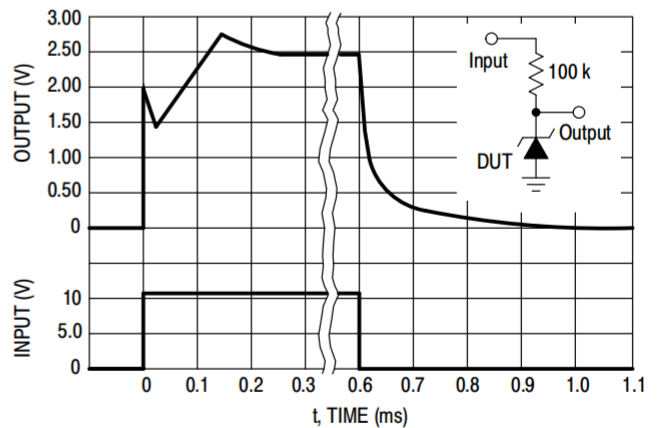
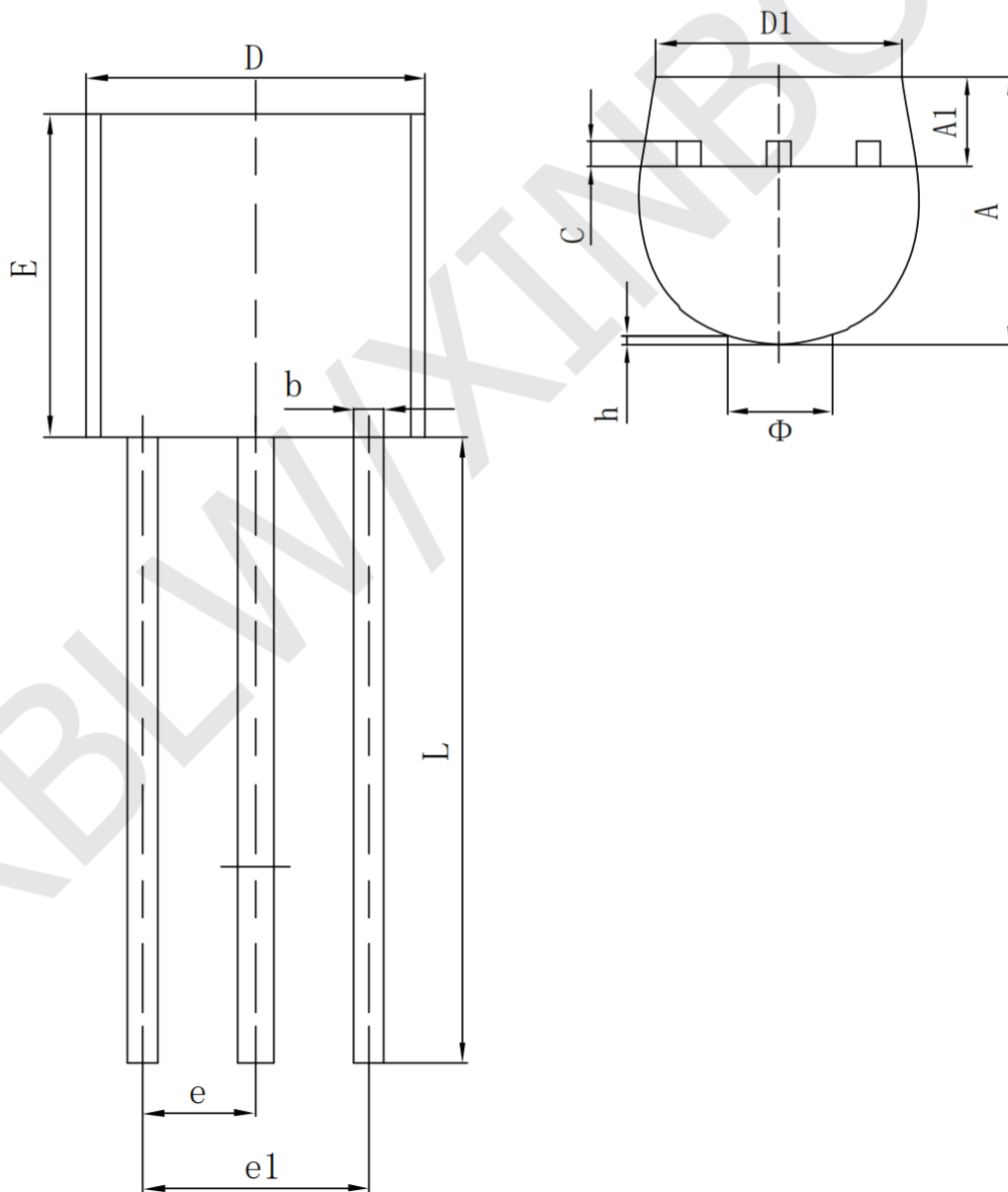


Figure 13. Response Time

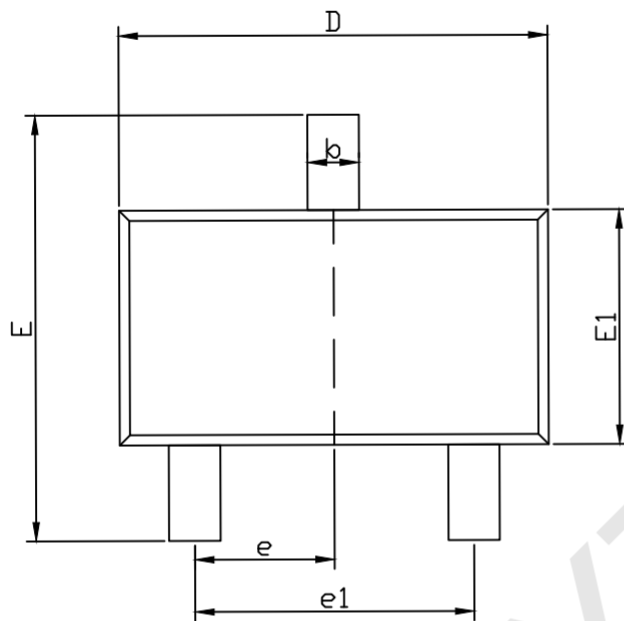
Package Information

· T0-92

Symbol	Size		Dimensions In Millimeters		Symbol	Size		Dimensions In Inches	
			Min(mm)	Max(mm)				Min(in)	Max(in)
A			3.300	3.700	A			0.130	0.146
A1			1.100	1.400	A1			0.043	0.055
b			0.380	0.550	b			0.015	0.022
c			0.360	0.510	c			0.014	0.020
D			4.300	4.700	D			0.169	0.185
D1			3.430		D1			0.135	
E			4.300	4.700	E			0.169	0.185
e			1.270(TYP)		e			0.050(TYP)	
e1			2.440	2.640	e1			0.096	0.104
L			14.10	14.50	L			0.555	0.571
Φ				1.600	Φ				0.063
h			0.000	0.380	h			0.000	0.015

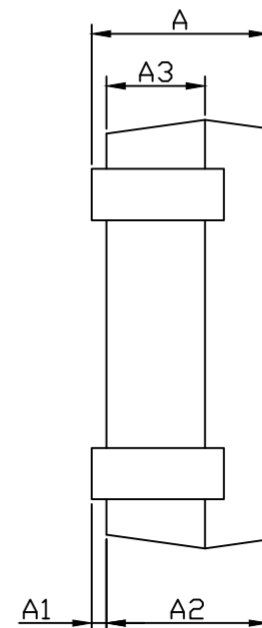
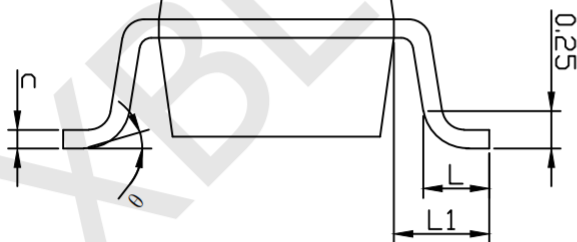


• SOT23-3L



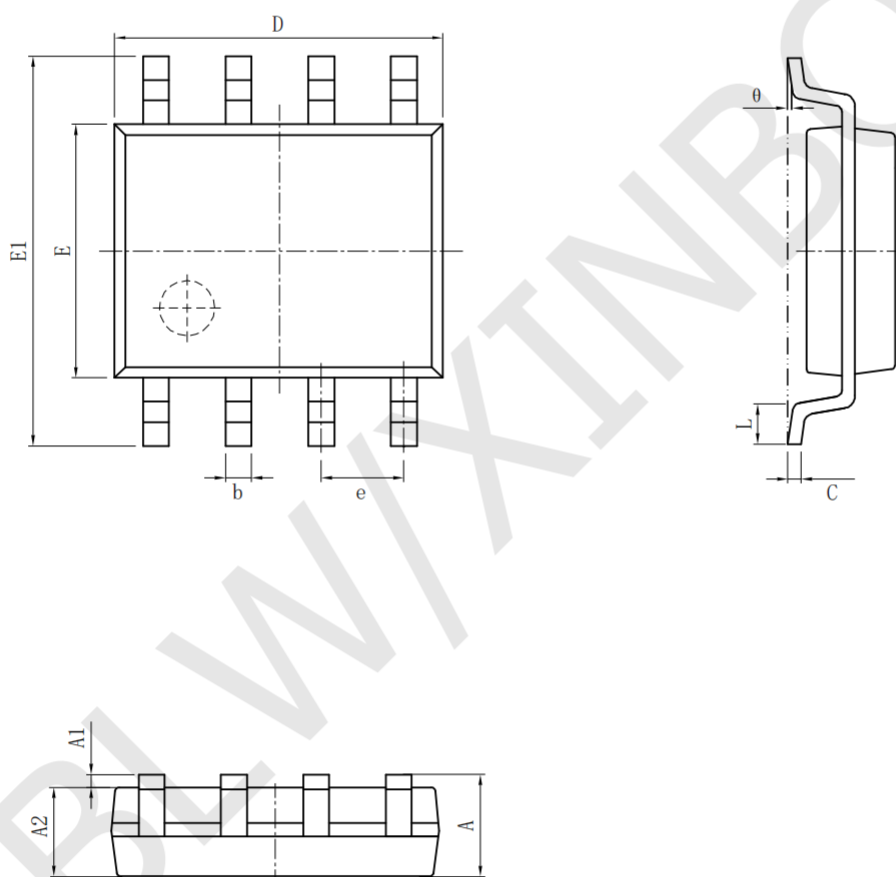
COMMON DIMENSIONS
(UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX
A	-	-	1.25
*A1	0.01	-	0.08
A2	1.00	1.10	1.20
A3	0.60	0.65	0.70
b	0.33	-	0.41
c	0.11	-	0.20
D	2.82	2.92	3.02
*E	2.60	2.80	3.00
*E1	1.50	1.60	1.70
*e	0.90	0.95	1.00
e1	1.90BSC		
L	0.30	-	0.60
*L1	0.55	0.60	0.75
θ	0°	-	8°



• SOP-8

Size Symbol	Dimensions In Millimeters		Size Symbol	Dimensions In Inches	
	Min (mm)	Max (mm)		Min (in)	Max (in)
A	1.350	1.750	A	0.053	0.069
A1	0.100	0.250	A1	0.004	0.010
A2	1.350	1.550	A2	0.053	0.061
b	0.330	0.510	b	0.013	0.020
c	0.170	0.250	c	0.006	0.010
D	4.700	5.100	D	0.185	0.200
E	3.800	4.000	E	0.150	0.157
E1	5.800	6.200	E1	0.228	0.224
e	1.270 (BSC)		e	0.050 (BSC)	
L	0.400	1.270	L	0.016	0.050
θ	0°	8°	θ	0°	8°



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